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SerDes" FIN212AC 12-Bit Serializer / Deserializer Supporting Cameras and **Small Displays**

Features

Data & Control Bits	12-Bit
Frequency	40MHz
Capability	Camera or LCD
Interface	Microcontroller, RGB, YUV
µController Usage	m68 & i86
Selectable Edge Rates	Yes
Standby Current	<10 µA
Core Voltage (V _{DDA/S})	2.5 to 3.6V
I/O Voltage (V _{DDP})	1.65 to 3.6V
ESD (I/O to GND)	14kV
Dookogo	32-Terminal MLP
Package	42-Ball USS-BGA
Ordering Information	FIN212ACMLX
Ordering Information	FIN212ACGFX

Description

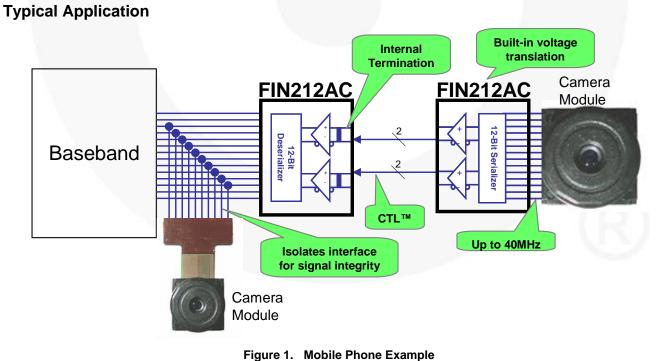
The FIN212AC µSerDes™ is a low-power serializer / deserializer optimized for use in cell phone displays and camera paths. The device reduces a 12-bit data path to four wires. For camera applications, an additional master clock can be passed in the opposite direction of data flow. The device utilizes Fairchild's proprietary ultra-low power, low-EMI technology.

Applications

- Slider, Folder, & Clamshell Mobile Handsets
- Printers .
- Security Cameras

Related Resources

For samples and questions, please contact: Interface@fairchildsemi.com.



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FIN212AC • Rev. 1.1.1

March 2013

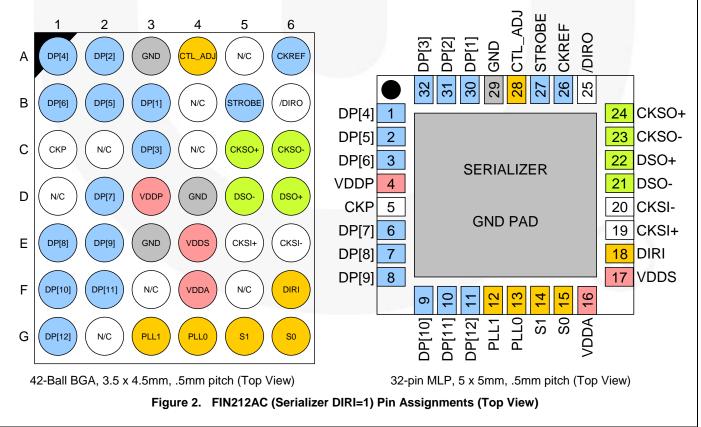
Pin Name	Description							
DIRI	Control to determine serializer or deserializer configuration.	0	Deserializer					
		1 5	Serializer					
CTL_ADJ	Adjusts CTL drive to compensate for environmental conditions	0 1	Low drive (low power)					
CIL_ADJ	and length.	1	High drive (high power)					
S0	Configure frequency range for the PLL.	See	e Table 1 Serializer (DIRI=1) Control Pin.					
S1	Configure frequency range for the PLL.	See	e Table 1 Serializer (DIRI=1) Control Pin.					
PLL0	Divide or adjust the serial frequency.	See	e Table 1 Serializer (DIRI=1) Control Pin.					
PLL1	Divide or adjust the serial frequency.	Divide or adjust the serial frequency. See Table 1 Serializer (DIRI=1) Control Pin.						
CKREF	LV-CMOS clock input and PLL reference.							
STROBE	LV-CMOS strobe input for latching data (DP [1:12]) into the seria	lizer or	n the rising edge.					
DP[1:12]	LV-CMOS parallel data input. (GND input if not used)							
CKSO+	CTL Differential serializer output bit clock.							
CKSO-	CKSO+: Positive signal; CKSO-: Negative signal.							
DSO+	CTL Differential serial output data signals.							
DSO-	DSO+: Positive signal; DSO-: Negative signal.							
CKSI+	CTL Differential deserializer input bit clock.	No	connect unless in "clock pass-through" mode.					
CKSI-	CKSI+: Positive signal; CKSI-: Negative signal.		, ,					
СКР	LV-CMOS word clock output or Pixel clock output.		connect unless in "clock pass-through" mode.					
/DIRO	LV-CMOS output, Inversion of DIRI in normal operation. Can be		o drive the DIRI signal No connect if not used					
	of the deserializer where the interface needs to be turned around							
VDDP	Power supply for parallel I/O. (All VDDP pins must be connected	l to VD	DDP)					
VDDS	Power supply for serial I/O.							
VDDA	Power supply for core.							
GND	All GND pins must be connected to ground. BGA: all GND pads.	MLP: I	Pin 29 & GND PAD must be grounded.					
N/C	No connect. (Do not connect to GND or VDD)							

FIN212AC (Serializer DIRI=1) Pin Descriptions

Note:

1. 0=GND; 1=VDDP

FIN212AC (Serializer DIRI=1) Pin Configurations



µSerDes™ FIN212AC

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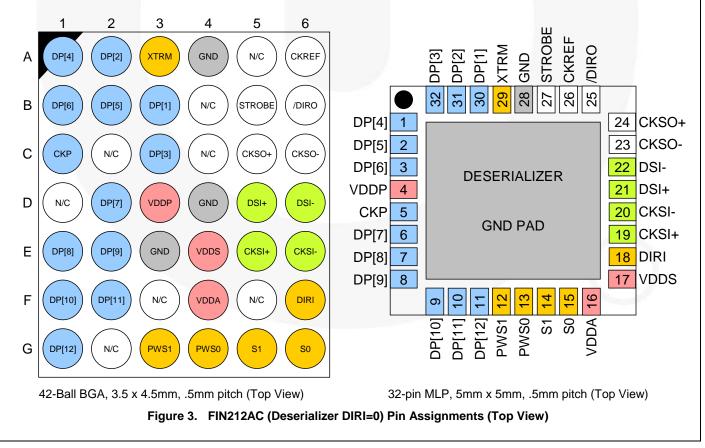
Pin Name	Description	
DIRI	Control to determine serializer or deserializer configuration.	0 Deserializer
Dirti		1 Serializer
XTERM	Control to determine if using internal or external termination	0 Internal termination used
		1 External termination required on CKSI & DSI
S0	Signals used to define the edge rate of parallel I/O.	See Table 2 Deserializer (DIRI=0) Control Pin.
S1	Signals used to define the edge rate of parallel I/O.	See Table 2 Deserializer (DIRI=0) Control Pin.
PWS0	Configure CKP pulse width.	See Table 2 Deserializer (DIRI=0) Control Pin.
PWS1	Configure CKP pulse width.	See Table 2 Deserializer (DIRI=0) Control Pin.
DP[1:12]	LV-CMOS parallel data output. (N/C if not used)	÷
CKP	LV-CMOS word clock output or Pixel clock output.	
DSI+	CTL Differential serial input data signals.	
DSI-	DSI+: Positive signal; DSI-: Negative signal.	
CKSI+	CTL Differential deserializer input bit clock.	
CKSI-	CKSI+: Positive signal; CKSI-: Negative signal.	
CKSO+	CTL Differential serializer output bit clock.	No connect unless in "clock pass-through" mode
CKSO-	CKSO+: Positive signal; CKSO-: Negative signal.	No connect unless in clock pass-tinough mode
CKREF	LV-CMOS clock input and PLL reference.	No connect unless in "clock pass-through" mode
STROBE	LV-CMOS strobe input for latching data into the serializer.	No connect unless in "clock pass-through" mode
/DIRO	LV-CMOS Output. Inversion of DIRI in normal operation.	No connect if not used.
VDDP	Power supply for parallel I/O. (All VDDP pins must be connected	d to VDDP)
VDDS	Power supply for serial I/O.	
VDDA	Power supply for core.	
GND	All GND pins must be connected to ground. BGA: all GND pads	. MLP: Pin 28, 29, GND PAD must be grounded.
N/C	No connect. BGA: G1, F2; MLP: 10, 11; (Do not connect to GNI	D or VDD)

FIN212AC (Deserializer DIRI=0) Pin Descriptions

Note:

2. 0=GND; 1=VDDP

FIN212AC (Deserializer DIRI=0) Pin Configurations



µSerDes™ FIN212AC —

System Control Pin

		Functio	on			Control Pin			
Conditions	CKREF	ST	TROBE	PLL Multiplier	PLL0	PLL1	S0	S1	
	S	low Frequenci	es						
Normal operation	5MHz to 14MHz	≤ CKREF	(Up to 14MHz)	1	1	0	0	1	
Supports spread spectrum on CKREF	4.7MHz to 13.3MHz	≤ CKREF (Up to 13.3MHz)	0.954	0	0	0	1	
With a fixed CKREF input; STROBE can be 1/2 the speed	5MHz to 14MHz	≤ CKREF /	2 (Up to 7MHz)	2	0	1	0	1	
With a fixed CKREF input; STROBE can be 1/3 the speed	5MHz to 14MHz	≤ CKREF / 3	(Up to 4.67MHz)	3	1	1	0	1	
	Ме	dium Frequend	cies	•				<u> </u>	
Normal operation	8MHz to 28MHz	≤ CKREF	(Up to 28MHz)	1	1	0	1	1	
Supports spread spectrum on CKREF	9.5MHz to 26.7MHz	≤ CKREF (Up to 26.7MHz)	0.954	0	0	1	1	
With a fixed CKREF input; STROBE can be 1/2 the speed	8MHz to 28MHz	≤ CKREF /	2 (Up to 14MHz)	2	0	1	1	1	
With a fixed CKREF input; STROBE can be 1/3 the speed	8MHz to 28MHz	≤ CKREF / 3	3 (Up to 9.3MHz)	3	1	1	1	1	
	F	ast Frequencie	es						
Normal operation	20MHz to 40MHz	≤ CKREF	(Up to 40MHz)	1	1	0	1	0	
Supports spread spectrum on CKREF	19MHz to 38.2MHz	≤ CKREF (Up to 38.2MHz)	0.954	0	0	1	0	
With a fixed CKREF input; STROBE can be 1/2 the speed	20MHz to 40MHz	≤ CKREF /	2 (Up to 20MHz)	2	0	1	1	0	
With a fixed CKREF input; STROBE can be 1/3 the speed	20MHz to 40MHz	≤ CKREF / 3	(Up to 13.3MHz)	3	1	1	1	0	
	Power-Down			<u> </u>	Х	Х	0	0	
Table 1: Serializer (DIRI=1) Cont	rol Pin								
	CKP Pulse Widt	h Low Time	Reference	e		Control Pi	n		
LVCMOS Output CKP to Edge Rates STROBE	CKREF=19.2	CKREF=26	PLL Multiplier	Pwidth	PWS0	PWS1	S0	S1	

						001110111					
LVCMOS Output Edge Rates	CKP to STROBE	CKREF=19.2 MHz	CKREF=26 MHz	PLL Multiplier (Serializer)	Pwidth Multiplier	PWS0	PWS1	S0	S1		
	Slow Frequencies										
~7 – 8ns (C∟=8pF)	Non-Inverted	52.1ns	38.5ns	2	7	0	0	0	1		
· · · · · · · · · · · · · · · · · · ·	Inverted	52.1ns	38.5ns	2	7	1	0	0	1		
[Typically for 5MHz to	Non-Inverted	96.7ns	71.4ns	2	13	0	1	0	1		
14MHz signals]	Non-Inverted	126.5ns	93.4ns	2	17	1	1	0	1		
		N	ledium Frequen	cies							
~4 – 5ns (C _L =8pF)	Non-Inverted	78.1ns	57.7ns	3	7	0	0	1	1		
· · · · · · · · · · · · · · · · · · ·	Inverted	78.1ns	57.7ns	3	7	1	0	1	1		
[Typically for 8MHz to	Non-Inverted	145.1ns	107.1ns	3	13	0	1	1	1		
28MHz signals]	Non-Inverted	189.7ns	140.1ns	3	17	1	1	1	1		
			Fast Frequenci	es							
~2 – 3ns (C _L =8pF)	Non-Inverted	26ns	19.2ns	1	7	0	0	1	0		
(of ob.)	Inverted	26ns	19.2ns	1	7	1	0	1	0		
[Typically for 20MHz	Non-Inverted	48.4ns	35.7ns	1	13	0	1	1	0		
to 40MHz signals]	Non-Inverted	63.2ns	46.7ns	1	17	1	1	1	0		
	Power-Down										

Table 2: Deserializer (DIRI=0) Control Pin

CKP Pulse Width Low Time=(PLL Multiplier * Pwidth Multiplier) / (CKREF*14)	

Example: CKREF=26MHz; PLL Multiplier=2; Pwidth Multiplier=13

CKP Pulse width=(2 * 13) / (26MHz * 14)=71.4ns

(2)

(1)

Power-Down States

When both S1 and S0 signals are 0, regardless of the state of the DIRI signal, the FIN212AC resets and powers down. The power-down mode shuts down all internal analog circuitry, disables the serial input and output of the device, and resets all internal digital logic. Table 3: Power-Down indicates the state of the input states and output buffers in Power-Down mode.

Signal Pins	DIRI=1 (Serializer)	DIRI=0 (Deserializer)
DP[12:1]	Inputs Disabled	High-Z
СКР	HIGH	High-Z
STROBE	Input Disabled	Input Disabled
CKREF	Input Disabled	Input Disabled
/DIRO	0	1

Table 3: Power-Down

Clock Pass-Through Mode

Clock pass-through mode allows a harmonic rich clock source to be sent to the serializer in a CTL format to reduce the overall harmonic content of the phone, and can reduce the need for EMI filters. The Master Clock Pass through mode performs a translation to the clock in the CTL link, and does not serialize this signal. The following describes how to enable this functionality for an image sensor (See Figure 6).

Deserializer Configuration (DIRI=0)

- 1. Connect CKREF(BGA pin A6) to GROUND
- 2. Connect master clock to STROBE (BGA pin B5)

Serializer Configuration (DIRI=1)

1. CKSI passes master clock to CKP output (BGA pin C1)

CKREF and STROBE Signals

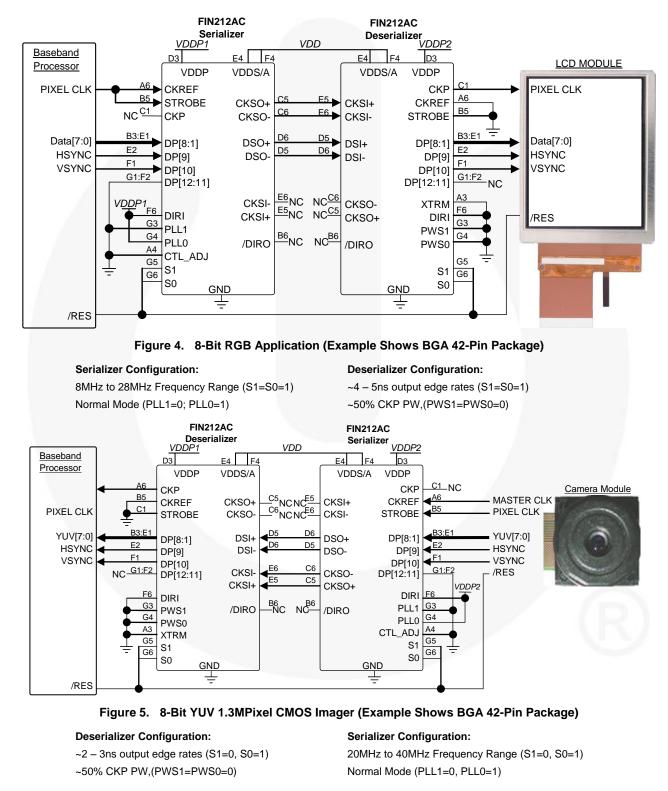
Please note that there is a setup and hold time between STROBE and data that must be met as seen on the electrical characteristics section. The relationship between CKREF and STROBE can be synchronous or asynchronous depending on what is available in the system. It is suggested that if the signals are synchronous and in normal operation that CKREF is tied to STROBE as close to the chip as possible. If you are running an asynchronous or spread spectrum setup, please be aware this may result on cycle jitter on the CKP signal. They cycle jitter does not effect the output data and clock relationship, the display or end application should continue to work as normal.

PLL Note

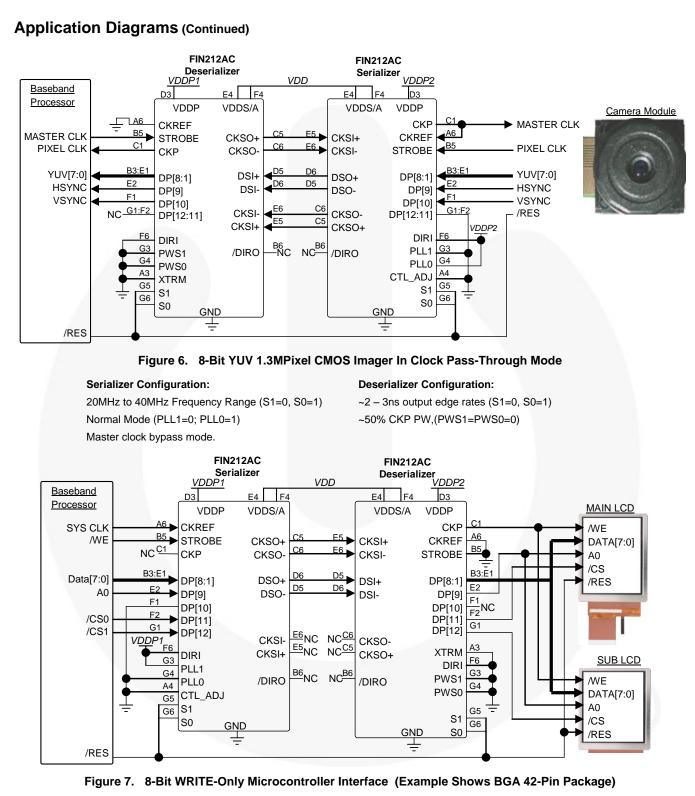
Please note that the PLL ranges can overlap, power consumption can be reduced by selecting the operation in the lower end of the higher speed PLL range.

Application Diagrams

The following application diagrams illustrate the most typical applications for the FIN212 device. Specific configurations of the control pins may vary based on the needs of a given system. The following recommendations are valid for all of the applications shown.



µSerDes™ FIN212AC —



Serializer Configuration:

20MHz to 40MHz Frequency Range (S1=0, S0=1) CKREF is twice as fast STROBE (PLL1=1; PLL0=0) CKREF=26MHz & STROBE Frequency=10 MHz

Deserializer Configuration:

~7 - 8ns output edge rates (S1=1, S0=0) ~50% CKP PW,(PWS1=PWS0=0) µSerDes™ FIN212AC —

Additional Application Information

Flex Cabling: The serial I/O information is transmitted at a high serial rate. Care must be taken implementing this serial I/O flex cable. The following best practices should be used when developing the flex cabling or Flex PCB.

- Keep all four differential Serial Wires the same length.
- Do not allow noisy signals over or near differential serial wires. Example: No LVCMOS traces over differential serial wires.
- Use only one ground plane or wire over the differential serial wires. Do not run ground over top and bottom.
- Design goal of 100Ω differential characteristic impedance.
- Do not place test points on differential serial wires.
- Use differential serial wires a minimum of 2cm away from the antenna.
- For additional applications notes or flex guidelines see your sales representative or contact Fairchild directly.
- For samples and questions, please contact: <u>Interface@fairchildsemi.com</u>.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paramet	er	Min.	Max.	Unit
V _{DD}	Supply Voltage		-0.5V	+4.6	V
	All Input/Output Voltage		-0.5	V _{DD} +0.5	V
	CTL Output Short-Circuit Duration		Continuous		
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Maximum Junction Temperature		+150		°C
TL	Lead Temperature (Soldering, four se	conds)	+260		°C
	Liveran Dady Madal JECD22 A444	Serial I/O Pins to GND		14	kV
ESD	Human Body Model JESD22-A114	All Pins		8	kV
	Charged Device Model, JESD22-C10	Charged Device Model, JESD22-C101			kV

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{DDA}, V_{DDS}	Supply Voltage	2.5	3.6	V
V _{DDP}	Supply Voltage	1.65	3.60	V
T _A	Operating Temperature	-30	+70	°C
V _{DDA-PP}	Supply Noise Voltage	100		mV _{PP}

DC Electrical Characteristics

Values are provided for over-supply voltage and operating temperature ranges, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min.	Тур. ⁽³⁾	Max.	Unit
LVCMOS I/C	0					
V _{IH}	Input High Voltage		$0.65 x V_{DDP}$		V _{DDP}	
VIL	Input Low Voltage		GND		$0.35 \mathrm{xV}_{\mathrm{DDP}}$	V

DC Electrical Characteristics (Continued)

			,				
			I _{OH} =-2.0mA, S1=0,S0=1				
V _{OH}	Output High Voltag	ge	I _{OH} =-0.4mA, S1=1,S0=0	$0.75 \mathrm{xV}_{\mathrm{DDP}}$		V _{DDP}	V
			I _{OH} =-1.0mA, S1=1,S0=1				
			I _{OL} =2.0mA, S1=0,S0=1				
V _{OL}	Output Low Voltag	je	I _{OL} =0.4mA, S1=1,S0=0	0		$0.25 \text{xV}_{\text{DDP}}$	V
			I _{OL} =1.0mA, S1=1,S0=1				
I _{IN}	Input Current		V _{IN} = 0V to 3.6V	-5.0		5.0	μA
DIFFEREN	ITIAL I/O						•
	Output HIGH	V 1.0V	CTL_ADJ=0		-2		
I _{ODH}	Source Current	V _{os} =1.0V	CTL_ADJ=1		-3.4		mA
1	Output LOW	V −1 0V	CTL_ADJ=0		1.2		mA
ODL	Sink Current	V _{OS} =1.0V	CTL_ADJ=1		2		IIIA
V_{GO}	Input Voltage Grou	und Offset ⁽⁴⁾			0		V
р	CKS Internal Rece	eiver	V_{ID} =50mV, V_{IC} =925mV,	80	100	120	Ω
K TRM	R _{TRM} Termination Resis		DIRI=0	80	100	120	12
	DS Internal Receiv	ver	V_{ID} =50mV, V_{IC} =925mV,	80	100	120	Ω
	Termination Resis	tor	DIRI=0	80	100	120	12

Notes:

 Typical values are given for V_{DD}=2.775V and T_A=25°C. Positive current values refer to the current flowing into the device and negative values refer to the current flowing out of pins. Voltages are referenced to GROUND unless otherwise specified (except ΔV_{OD} and V_{OD}).

4. V_{GO} is the difference in device ground levels between the CTL driver and the CTL receiver.

Power Supply Currents

Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Unit
I _{DD_PD}	V _{DD} Power-Down Supply Current	S1=S0=0, All Inputs at GND or	VDD			0.1		μA
			S1=L	20MHz		13		mA
I _{DD_SER1}			S0=H	40MHz		19		mA
	Dynamic Serializer Power Supply	f _{CKREF} =f _{STRB} , PLL1=0,PLL0=1;	S1=H S0=L	5MHz		9.5	1	mA
	Current	CTL_ADJ=0; C∟=0pF		14MHz		17		mA
			S1=H S0=H	8MHz		11		mA
				28MHz		20		mA
			S1=L S0=H	20MHz		10		mA
				40MHz		14		mA
	Dynamic Deserializer Power	f _{CKREF} =f _{STRB} , PLL1=0, PLL0=1;	S1=H	5MHz		8		mA
DD_DES1	Supply Current	CTL_ADJ=0; C _L =0pF	S0=L	14MHz		9		mA
			S1=H	8MHz		9	_	mA
			S0=H	28MHz		12		mA

Pin Capacitance Tables

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
$C_{\text{IN}},C_{\text{IO}},C_{\text{IO-DIFF}}$	Capacitance of Input Only Signals; Parallel Port Pins DP[1:10]; Differential I/O	DIRI=1, S1=0, S0=0, V _{DD} =2.5V		2		pF

AC Electrical Characteristics

Values are provided for over-supply voltage and operating temperature ranges, unless otherwise specified.

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit	
Serializer	Input Operating Conditions							_
			S1=0,	S0=1	18		40	
f_{CKREF}	CKREF Clock Frequency (5MHz - >40MHz);	f _{ckref} =f _{strb}	S1=1,	S0=0	5		14	MH
			S1=1,	S0=1	10		28	
			PLL1=	0, PLL0=0			100	
	Strobe Frequency Relative to		PLL1=	0, PLL0=1			100	% c
f _{STRB}	CKREF Frequency	f _{ckref} ≠ f _{strb}	PLL1=	1, PLL0=0			50	f _{CKRE}
			PLL1=	1, PLL0=1			33 ¹ / ₃	
t _{CPWH}	CKREF DC	T=1/f _{CKREF}			0.2	0.5	0.8	Т
t _{CPWL}	CKREF DC	T=1/f _{CKREF}		1	0.2	0.5	0.8	Т
t _{CLKT}	LVCMOS Input Transition Time ⁽⁵⁾	10-90%					20	ns
t _{SPWH/L}	STROBE Pulse Width HIGH/LOW	T=1/f _{CKREF}			T x ⁴ / ₁₄		T x ¹⁰ / ₁₄	ns
t _{stc}	DP _(n) Setup to STROBE (DIRI=1, f=5MHz)	Setup Time STROBE DP[1:12] X		Data	2.5			ns
t _{HTC}	DP _(n) Hold to STROBE (DIRI=1, f=5MHz)	Hold Time STROBE DP[1:12]		← t _{HTC}	2.0			ns
Serializer	AC Electrical Characteristics							
t _{TCCD}	Transmitter Clock Input to Clock Output Delay ⁽⁶⁾	CKS- CKS+ CKP	OBE=CKREF	VDD/2	21a+1.5		23a+6.5	ns
Phase Lo	ock Loop (PLL) AC Electrical Characteris	stics			1			
t _{TPLLS0}	Serializer PLL Stabilization Time	CKREF toggling a	nd stable		200		600	μs
t _{TPLLD0}	PLL Disable Time Loss of Clock			1			30.0	μs
t _{TPLLD1}	PLL Power-Down Time			20			20.0	ns
Deserializ	zer AC Electrical Characteristics							
Symbol	Parameter	Test Cond	tions		Min.	Ту	o. Max.	Ur
	Data Valid → ← t _{PDV}		PWS1	PWS0				
	СКР	- f _{STRB} =f _{CKREF}	0	0	7a-3		7a+3	
t _{RCOL}		f _{STRB} =f _{CKREF}	0	1	7a-3		7a+3	n
	DP[1:12] Data X		KREF 1	0	13a-3		13a+3	
		f _{STRB} =.5x f _{Cl}		1	17a-3		17a+3	_
				1				

AC Electrical Characteristics (Continued)

Γ				S1=0,S0=1	3	
	t _{RFD}	Output Rise/Fall Time Data (20% to 80%)	C _L =8pF	S1=1,S0=0	8	ns
			S1=1,S0=1	5		
Γ				S1=0,S0=1	2	
	t _{RFC} Output Rise/Fall Time CKP (20% to 80%)	C∟=8pF	S1=1,S0=0	7	ns	
				S1=1,S0=1	4	

Notes:

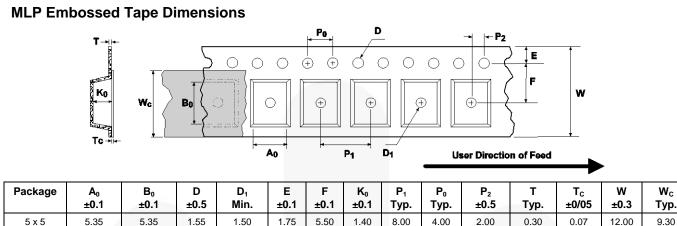
5. Parameter is characterized, but not production tested.

6. The average bit time "a" is a function of the serializer CKREF frequency; a=(1/f)/14.

Logic Timing Controls

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{PHL_DIR} , t _{PLH_DIR}	Propagation Delay DIRI to /DIRO	DIRI L->H or H->L			17	ns
$t_{\text{PLZ}},t_{\text{PHZ}}$	Propagation Delay DIRI to DP	DIRI L->H or H->L			25	ns
tdisdes	Deserializer Disable Time: S0 or S1 LOW to DPTri-State	; DIRI=0,			25	ns
t _{DISSER}	Serializer Disable Time: S0 or S1 LOW to CKP HIGH	DIRI=1; S1(0) and S0(1)=H->L			25	ns

Tape and Reel Specifications



6	х	6	

Notes:

 A_0 , B_0 , and K_0 dimensions are determined with respect to the EIA/JEDEC RS-481 rotational and lateral movement requirements (see sketches A, B, and C).

1.40

8.00

4.00

2.00

0.30

0.07

12.00

9.30

5.50

MLP Shipping Reel Dimensions

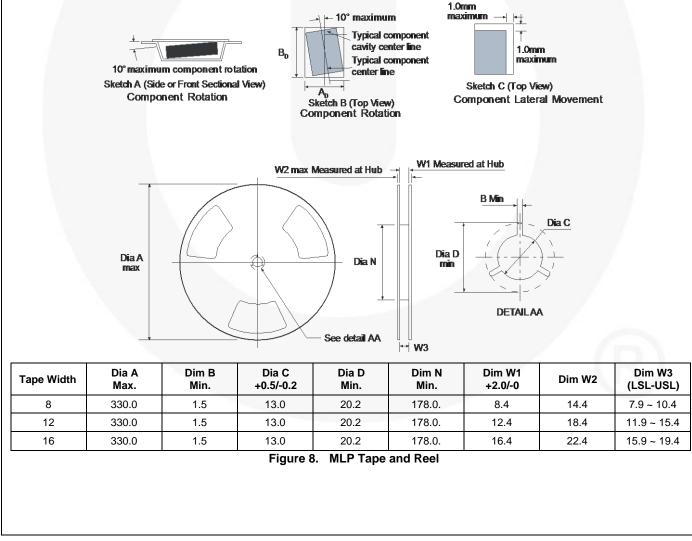
5.35

1.55

1.50

1.75

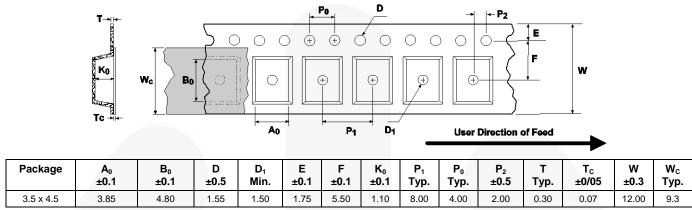
5.35



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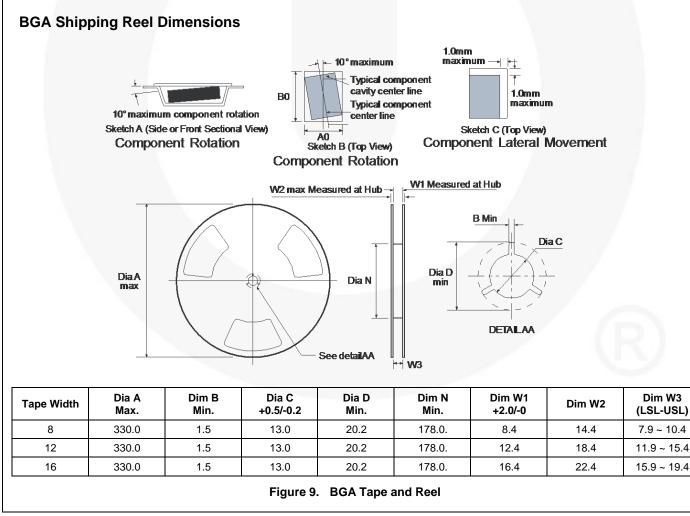
Tape and Reel Specifications (Continued)

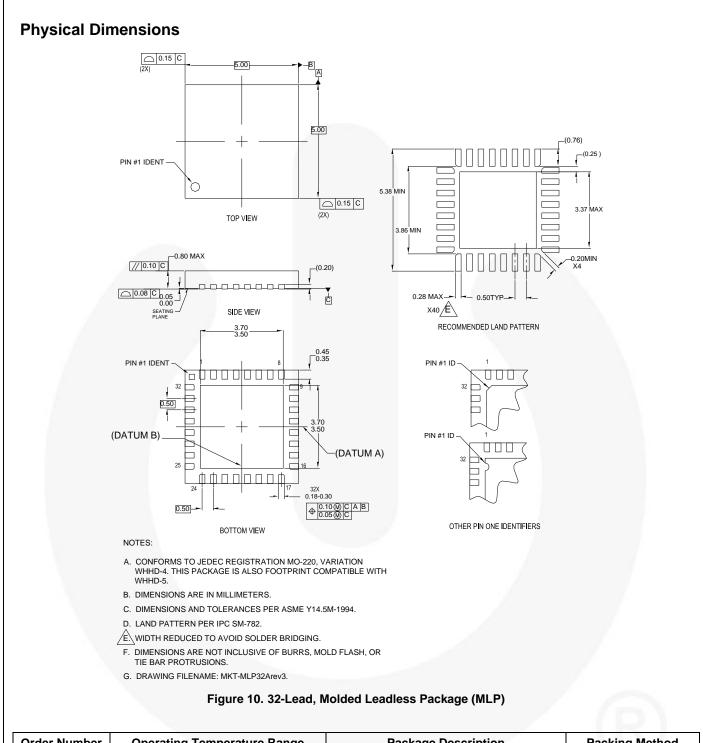
BGA Embossed Tape Dimensions



Notes:

 A_0 , B_0 , and K_0 dimensions are determined with respect to the EIA/JEDEC RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



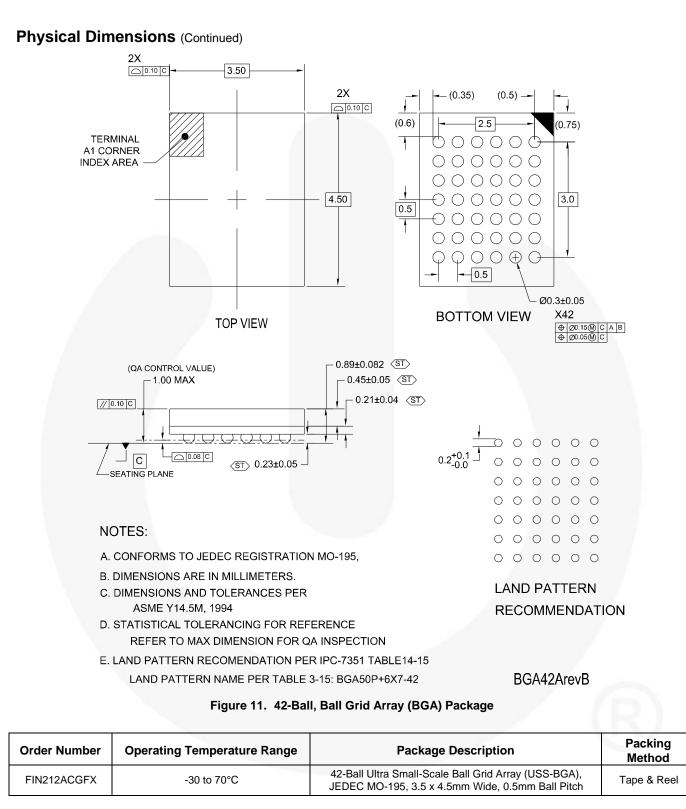


Order Number	Operating Temperature Range	Package Description	Packing Method
FIN212ACMLX	-30 to 70°C	32-Terminal Molded Leadless Package (MLP), Quad, JEDEC MO-220, 5mm Square	Tape & Reel

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